L Number	Hits	Search Text	DB	Time stamp
1	0	11040681.URPN.	USPAT	2003/01/13 14:46
2	2	5726087.pn.	USPAT; US-PGPUB;	2003/01/13 16:28
3	355	dry adj oxide	EPO; JPO; DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/01/13 16:49
4	518	(gate adj oxide) with angstrom with ("10" or "15" or "20")	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/01/13 16:51
5	341	(gate adj oxide) with angstrom with ("10" or "15")	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/01/13 17:23
6	234	((gate adj oxide) with angstrom with ("10" or "15")) and nitrid\$5	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/01/13 17:06
7	46	((gate adj oxide) with angstrom with ("10" or "15")) same nitrid\$5	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/01/13 17:06
8	8	(gate adj oxide) with angstrom with ("10" or "15") with (ultra near2 thin)	DERWENT USPAT; US-PGPUB; EPO; JPO;	2003/01/13 17:24
-	355	(gate with oxide) and (oxidiz\$3 with substrate) and (nitrid\$5 with (no or (nitric with oxide))) and cvd	DERWENT USPAT; EPO; JPO;	2003/01/13 12:28
-	197	((gate with oxide) and (oxidiz\$3 with substrate) and (nitrid\$5 with (no or (nitric with oxide))) and cvd) and temperature and (atm or atmosphere or	DERWENT USPAT; EPO; JPO; DERWENT	2002/07/30 14:02
_	149	torr) (((gate with oxide) and (oxidiz\$3 with substrate) and (nitrid\$5 with (no or (nitric with oxide))) and cvd) and temperature and (atm or atmosphere or	USPAT; EPO; JPO; DERWENT	2002/07/30 14:02
-	119	torr)) and 438/\$3.ccls. ((((gate with oxide) and (oxidiz\$3 with substrate) and (nitrid\$5 with (no or (nitric with oxide))) and cvd) and temperature and (atm or atmosphere or torr)) and 438/\$3.ccls.) and (gate with electrode)	USPAT; EPO; JPO; DERWENT	2002/07/30 13:55
_	145	(gate with oxide) same (oxidiz\$3 with substrate) and (nitrid\$5 with (no or (nitric with oxide))) and cvd	USPAT; EPO; JPO;	2002/07/31 15:55
-	76	((gate with oxide)) same (oxidiz\$3 with substrate) and (nitrid\$5 with (no or (nitric with oxide))) and cvd) and temperature and (atm or atmosphere or torr)	DERWENT USPAT; EPO; JPO; DERWENT	2002/07/30 14:02
-	59	(((gate with oxide) same (oxidiz\$3 with substrate) and (nitrid\$5 with (no or (nitric with oxide))) and cvd) and temperature and (atm or atmosphere or torr)) and 438/\$3.ccls.	USPAT; EPO; JPO; DERWENT	2002/07/30 14:02
-	5	(gate with oxide) same (oxidiz\$3 with substrate) and ((nitrid\$5 with (no or (nitric with oxide)) same boron)) and cvd	USPAT; EPO; JPO; DERWENT	2002/07/30 15:11
-	17	"5650344"	USPAT; EPO; JPO; DERWENT	2002/07/30 15:11
-	14	"5403786"	USPAT; EPO; JPO; DERWENT	2002/07/31 14:16

	1 06		T	
-	26	1 ,3	USPAT;	2002/07/31 15:57
		substrate) and (nitrid\$5 with (no or	EPO; JPO;	
		(nitric with oxide))) and cvd and ono and	DERWENT	!
		(gate adj electrode)		
 -	22	1 ,3 , , ,	USPAT;	2002/07/31 16:33
		substrate) and (nitrid\$5 with (no or	EPO; JPO;	
		(nitric with oxide))) and cvd and ono and	DERWENT	}
		((gate adj electrode) with (silicon or		
		polysilicon))		
-	11	((gate with oxide) same (oxidiz\$3 with	USPAT;	2002/07/31 15:58
İ		substrate) and (nitrid\$5 with (no or	EPO; JPO;	
		(nitric with oxide))) and cvd and ono and	DERWENT	
		((gate adj electrode) with (silicon or	ļ	
1		polysilicon))) and tungsten		
-	3	(gate with oxide) same (oxidiz\$3 with	USPAT;	2002/07/31 16:56
		substrate) and (nitrid\$5 with (no or	EPO; JPO;	
1		(nitric with oxide))) and cvd and ono and	DERWENT	
ļ		(((gate adj electrode) with polycide) same		
		tungsten)		
-	17	"5650344"	USPAT;	2002/07/31 16:56
			EPO; JPO;	
Ì			DERWENT	
-	3554	(nitrid\$5 with gate with oxide) and cvd	USPAT;	2003/01/13 12:32
			EPO; JPO;	
			DERWENT	
-	0	((nitrid\$5 with gate with oxide) same	USPAT;	2003/01/13 12:33
		(nitirc adj oxide)) and cvd	EPO; JPO;	
			DERWENT	
_	5	((nitrid\$5 with gate with oxide) same	USPAT;	2003/01/13 12:33
		(nitric adj oxide)) and cvd	EPO; JPO;	
			DERWENT	
-	6	((nitrid\$5 with gate with oxide) same	USPAT;	2003/01/13 14:55
1		(nitric adj oxide)) and cvd	US-PGPUB;	
			EPO; JPO;	
}			DERWENT	